



Safety and stability on LGADs

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•Detector Design

Requirements

What do we need to built a long running detector that work for several years?

Performance
Efficiency

Stability
Safety

Performance

- Time resolution $< 80\text{psec}$ per hit
- S/N of at least 5σ (10mV threshold for $\sim 1.8\text{mV}$ noise)

Efficiency

- Hit efficiency of at least 90%
- Sufficient available efficiency headroom

Stability

- Low or no auto triggering (false events) wrt the application
- Less than 1% auto trigger rate with respect to the actual event rate

Safety

- Operate in mean field less than $15\text{V}/\mu\text{m}$ \longrightarrow 750V max stable point for $50\mu\text{m}$
- Sensor not in breakdown \longrightarrow Either $dV/dI < 10$ or current multiplier < 2

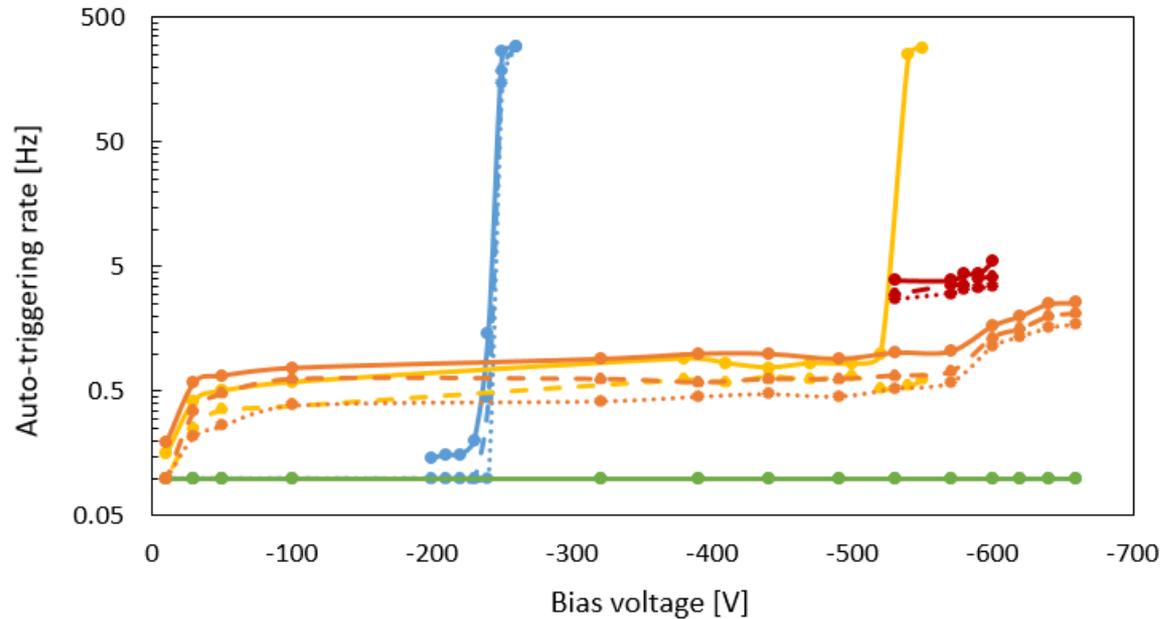
Operating point defined as 10% below breakdown

• Auto-trigger studies

Auto-trigger Frequency

Standard p-irradiated at -30C

p
irradiated



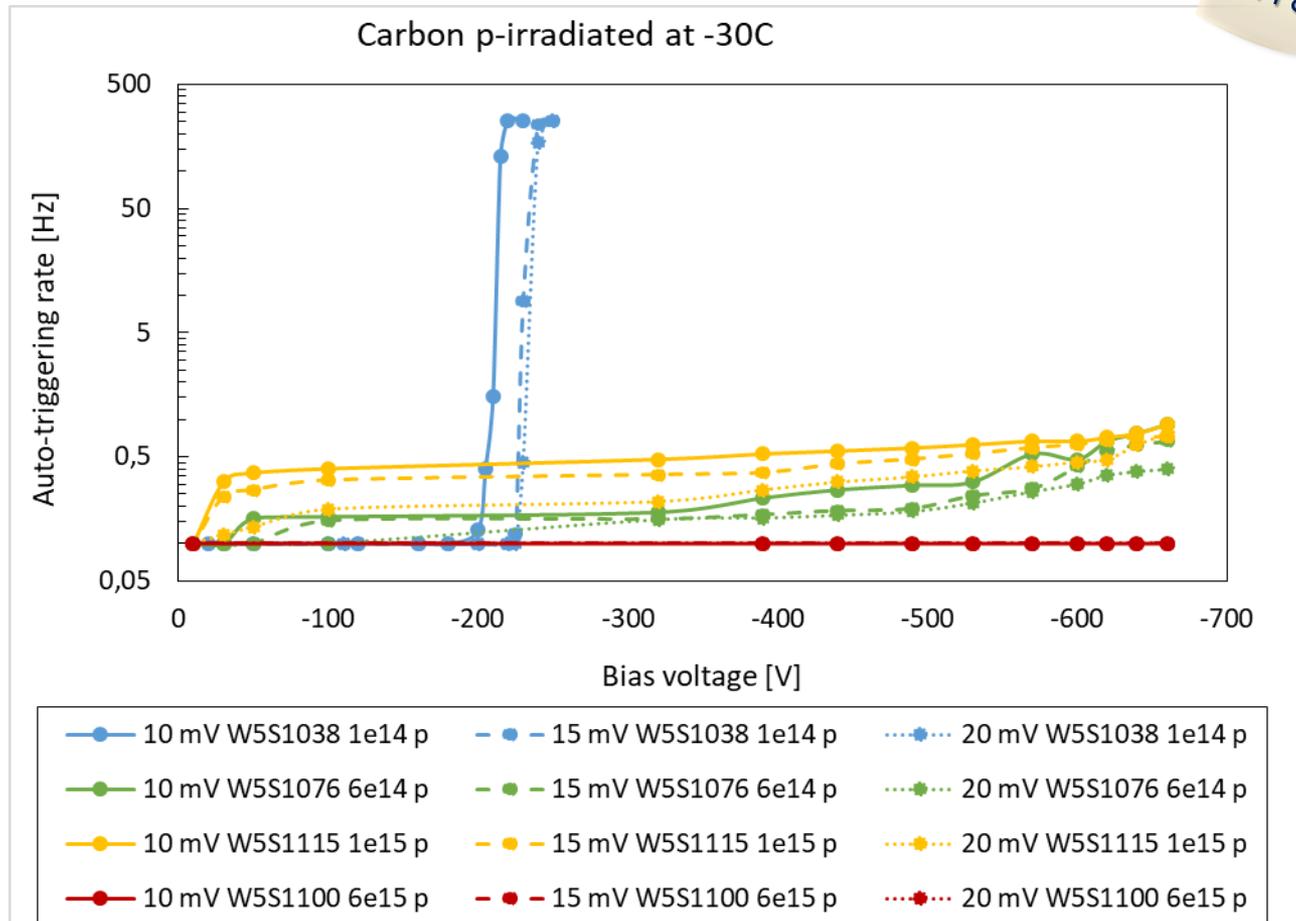
—●— 10 mV W4S1067 1e14 p	- -●- - 15 mV W4S1067 1e14 p	...●... 20 mV W4S1067 1e14 p
—●— 10 mV W4S1064 6e14 p	- -●- - 15 mV W4S1064 6e14 p	...●... 20 mV W4S1064 6e14 p
—●— 10 mV W4S1099 1e15 p	- -●- - 15 mV W4S1099 1e15 p	...●... 10 mV W4LG05 3e15 p
- -●- - 15 mV W4LG05 3e15 p	...●... 20 mV W4LG05 3e15 p	—●— 10 mV W4S1021 6e15 p
- -●- - 15 mV W4S1021 6e15 p	...●... 20 mV W4S1021 6e15 p	

- < 1000 events fro each point
- Three temperatures (-10°C, -20°C and - 30°C)
- Three thresholds (10,15 and 20 mV)

• Auto-trigger studies

Auto-trigger Frequency

p
irradiated



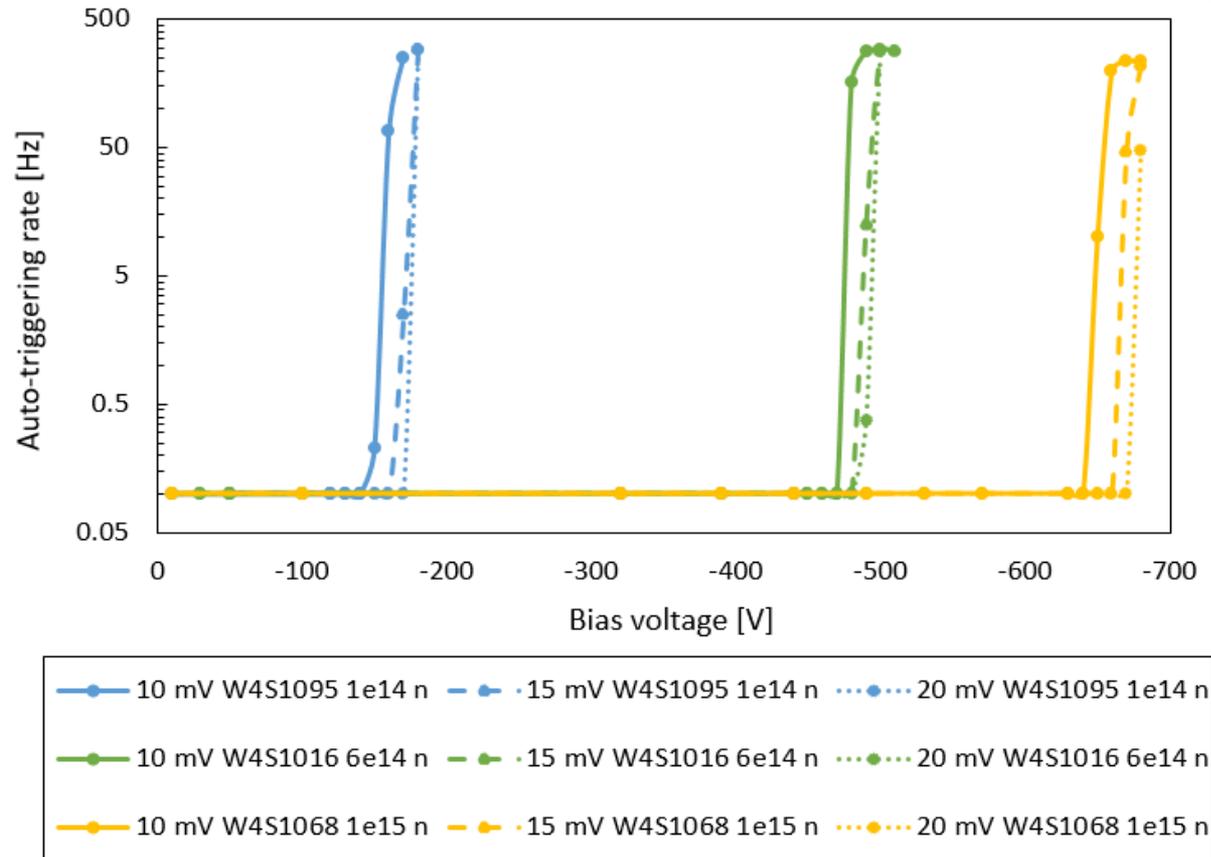
- < 1000 events fro each point
- Three temperatures (-10°C, -20°C and - 30°C)
- Three thresholds (10,15 and 20 mV)

• Auto-trigger studies

Auto-trigger Frequency

Standard n-irradiated at -30C

n irradiated

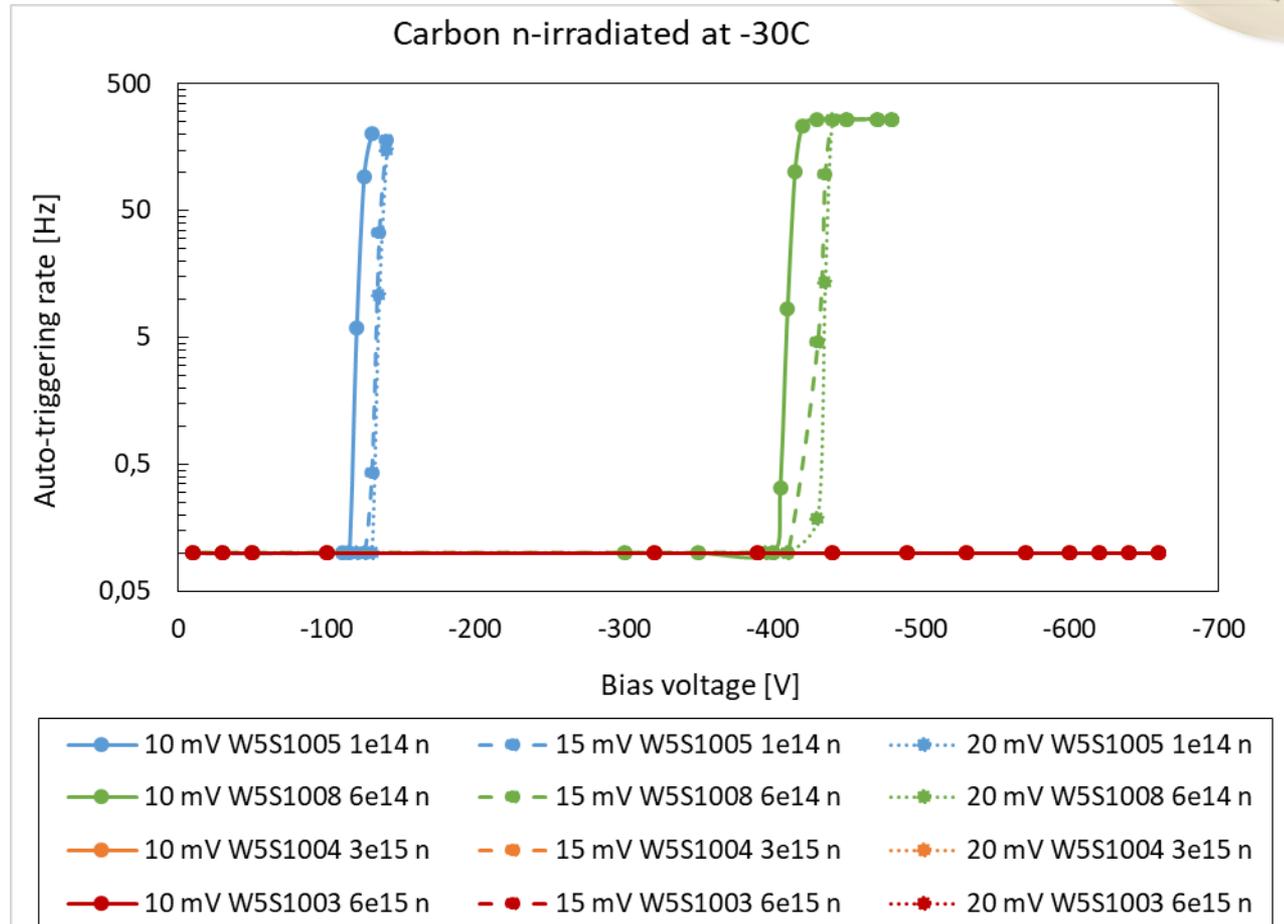


- < 1000 events fro each point
- Three temperatures (-10°C, -20°C and - 30°C)
- Three thresholds (10,15 and 20 mV)

• Auto-trigger studies

Auto-trigger Frequency

n
irradiated

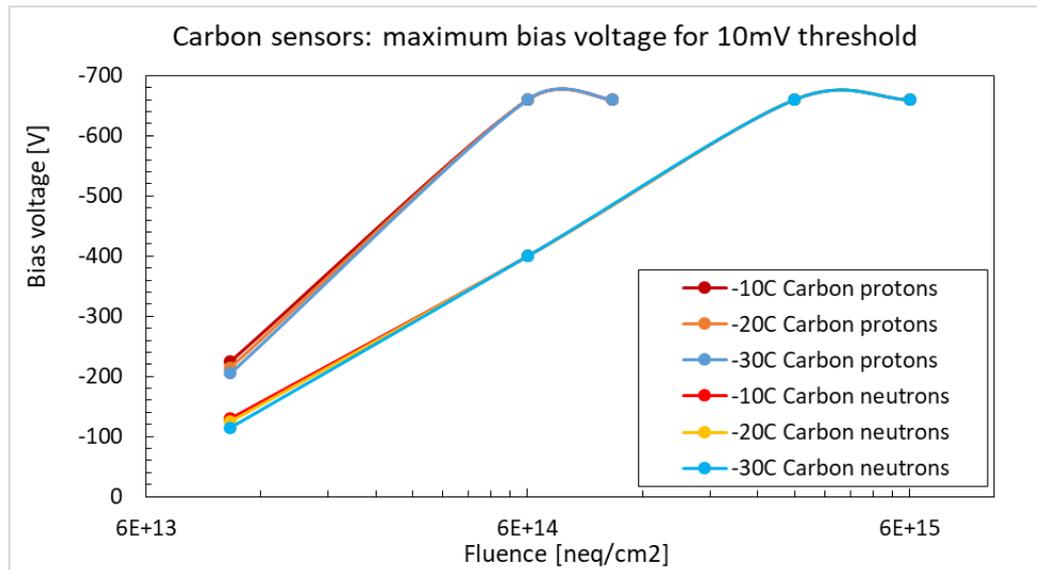
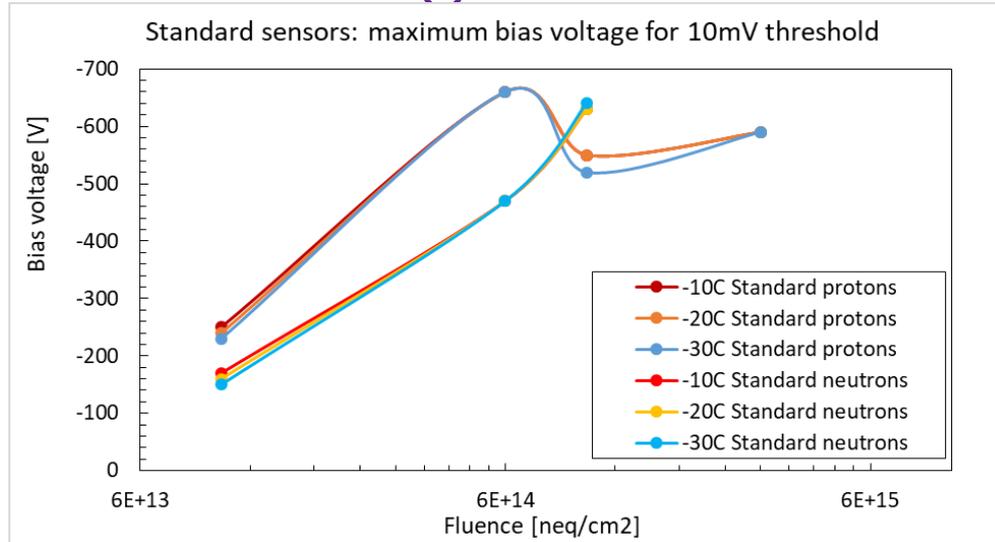


- < 1000 events fro each point
- Three temperatures (-10°C, -20°C and - 30°C)
- Three thresholds (10,15 and 20 mV)

•Auto-trigger studies

Maximum Voltage

n & p irradiated

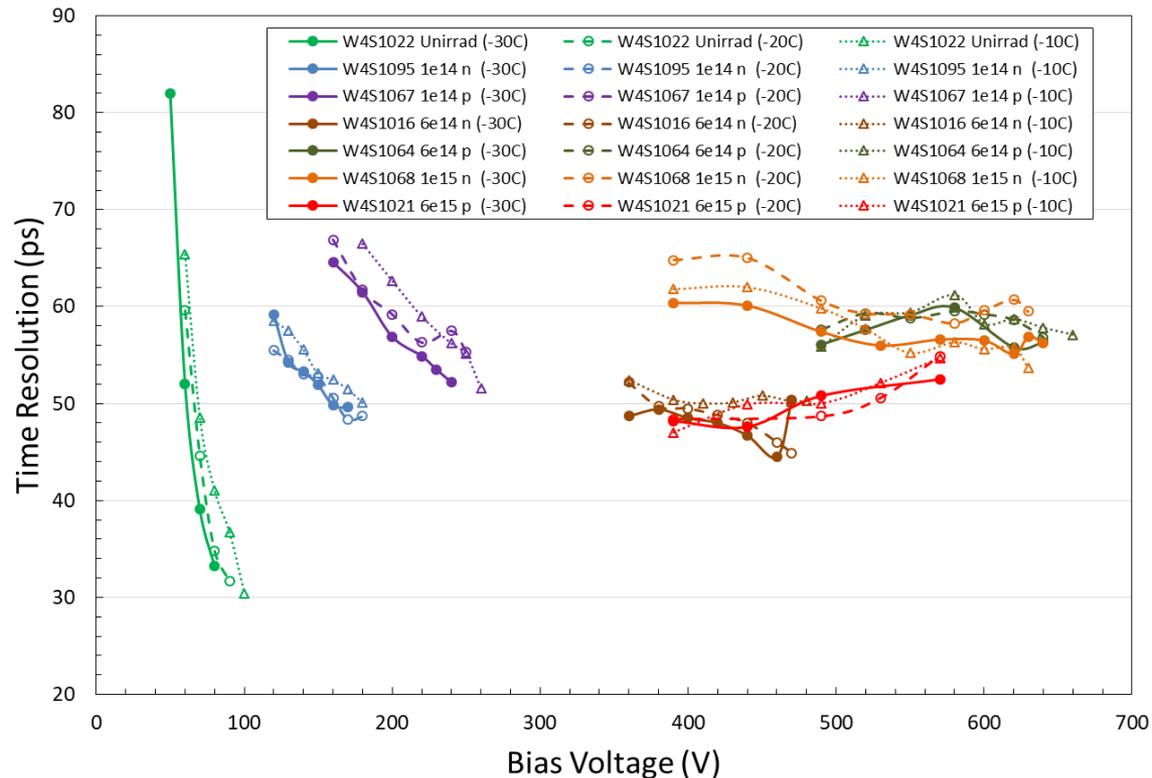


•Time resolution

Standard Boron

p + n
irradiated

CNM 10478 - Wafer 4 - Time Resolution

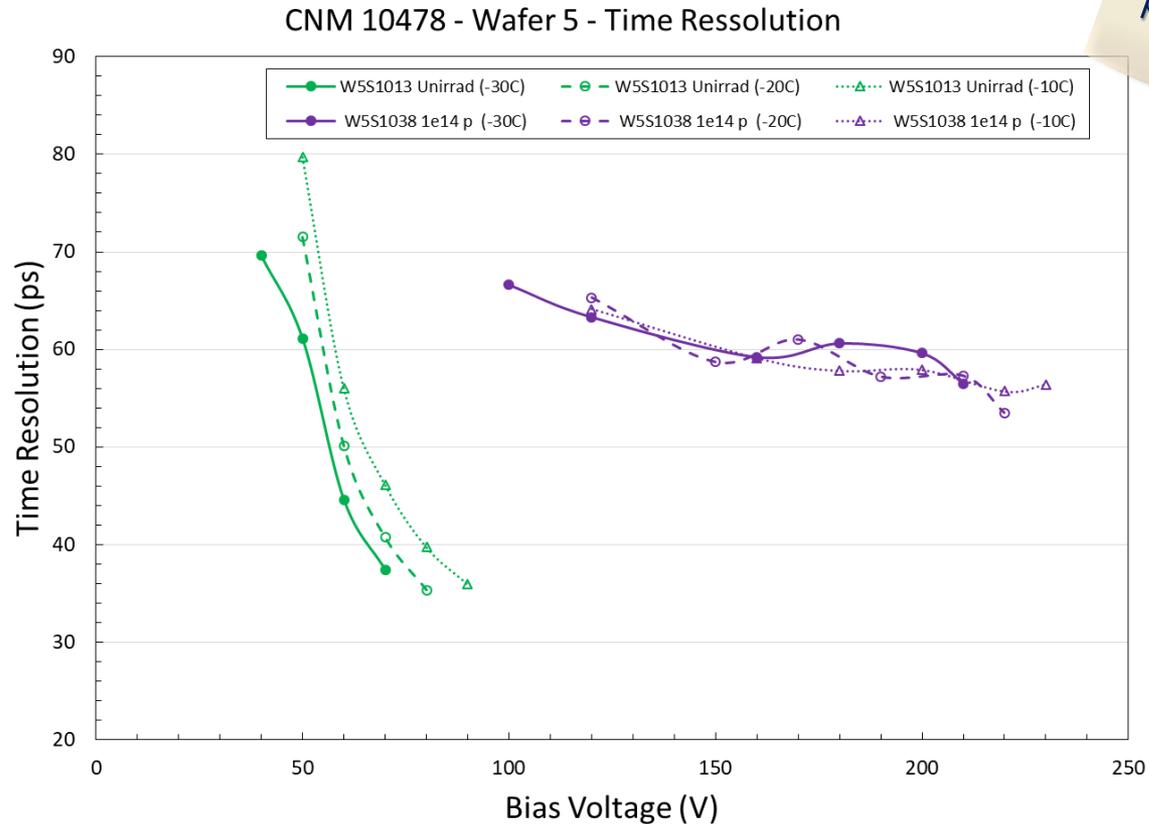


- < 5000 events from each point
- CFD @ 20% for un-irradiated and @ 50% for all irradiated to compare with test beam
- CFD percentage has been optimized separately for each point, time resolution ~ 1-2 psec better if optimized value used
- Three temperatures (-10°C, -20°C and -30°C)

•Time resolution

Carbon implanted

p irradiated



- 20% CFD for un-irradiated, 50% CFD for irradiated
- Maximum voltage set by self-triggering at 10mV threshold
- Amplitude cuts at $10\text{mv} < p_{\text{max}} < 200\text{mV}$
- Measurements on the rest of the samples ongoing

• Stable operation points and efficiency

Definitions

- Perform measurements with radioactive ^{90}Sr source
- Define stable operation points satisfying the following conditions:

Current multiplier < 2 for each point

Mean field inside sensor $< 15 \text{ V}/\mu\text{m}$

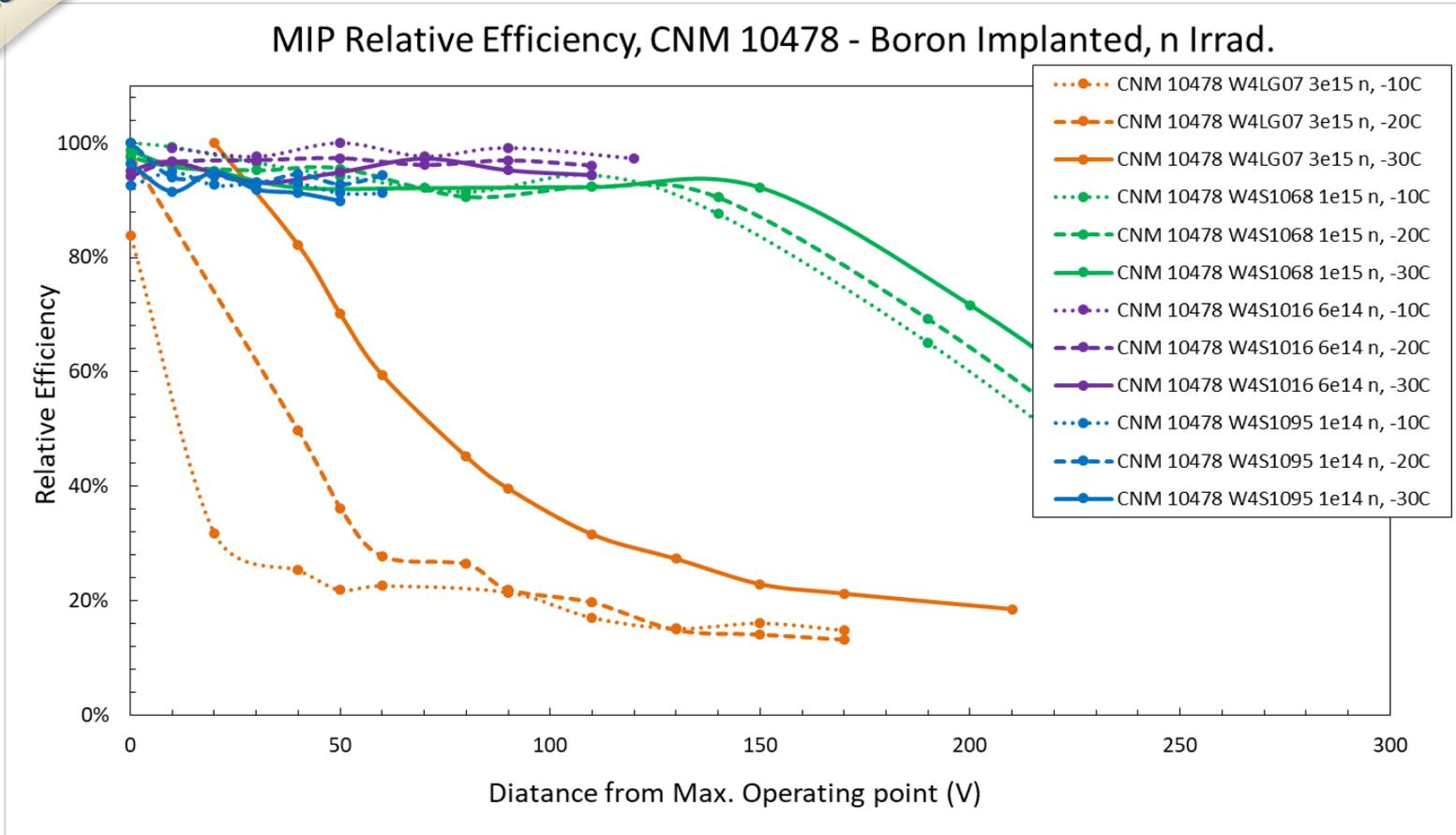
Autro-trigger rate $< 1\%$ of source trigger

- Repeat measurements for -10°C , -20°C & -30°C without changing setup
- Record for each voltage point time between consecutive triggers for 5k events
- Fit with exponential radioactive law and extract mean trigger period per point
- Define as 100% efficient point with highest rate
- Calculate the relative efficiency of all other points in all temperatures using as reference the most efficient point

•Relative efficiency – n Irradiated

CNM 10478, Wafer 4, Standard boron

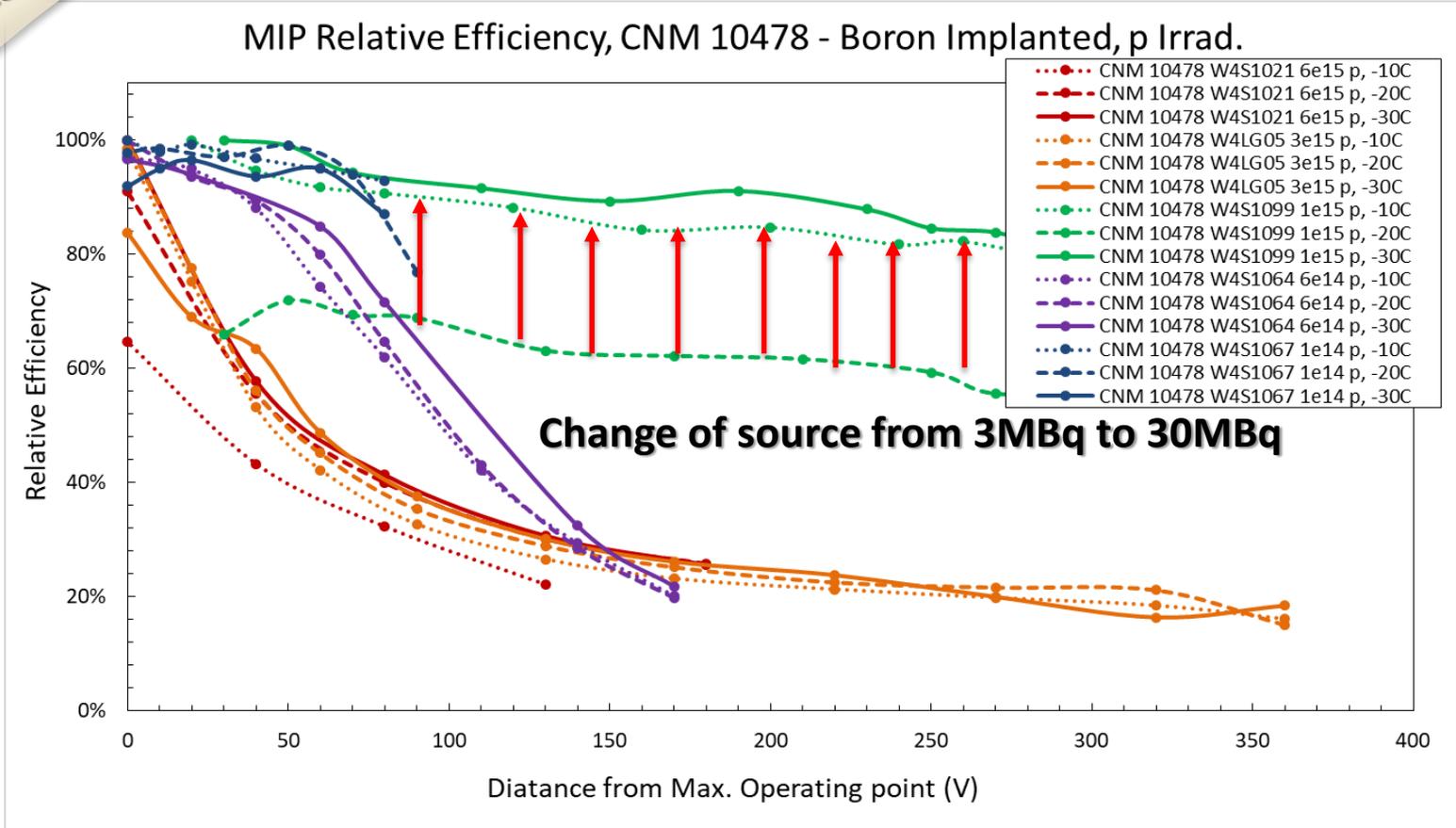
⁹⁰Sr source data



•Relative efficiency – p Irradiated

CNM 10478, Wafer 4, Standard boron

⁹⁰Sr source data

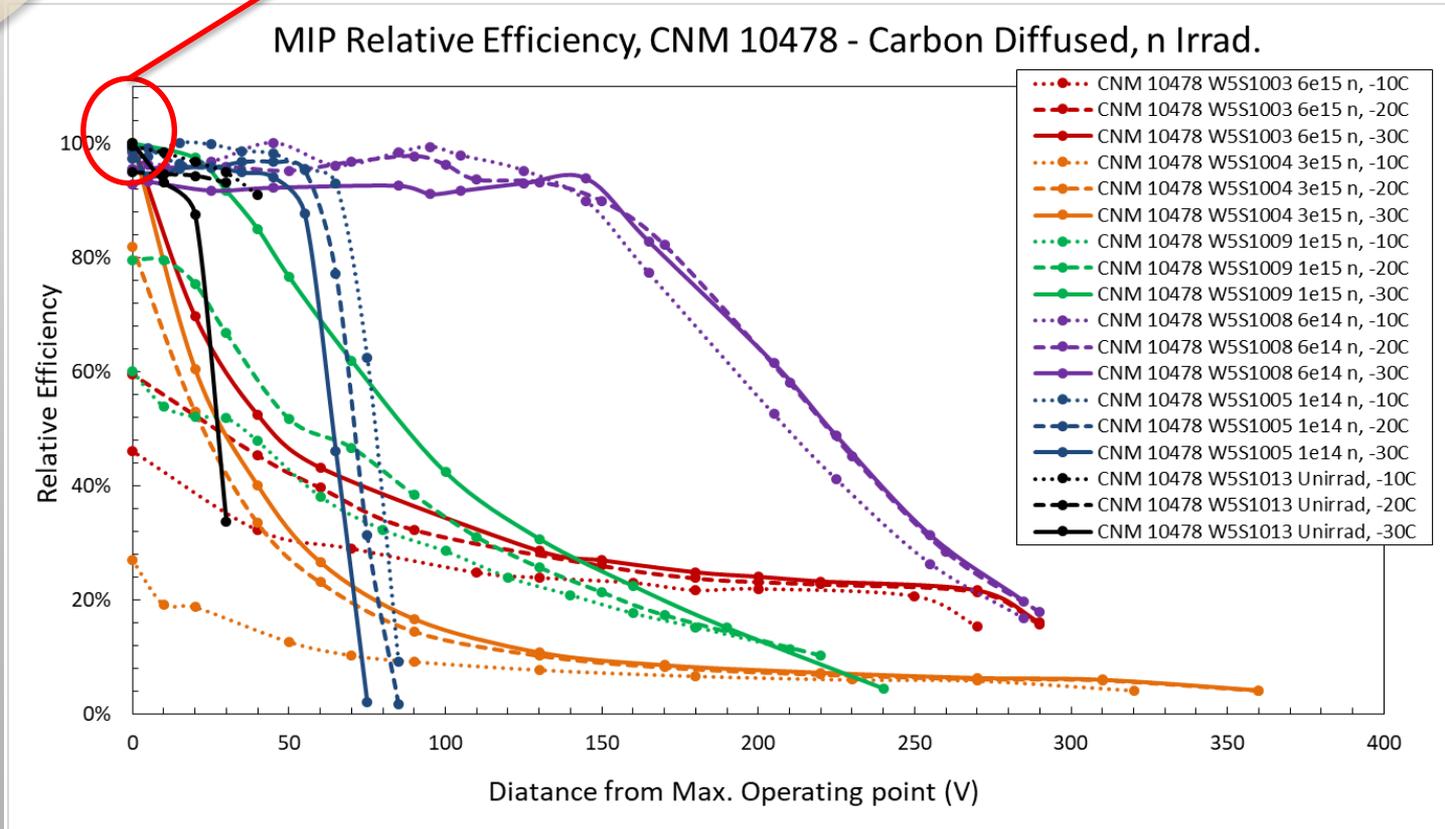


•Relative efficiency – n Irradiated

CNM 10478, Wafer 5, Carbon Implanted

90Sr source data

auto triggering (artificially increase efficiency)

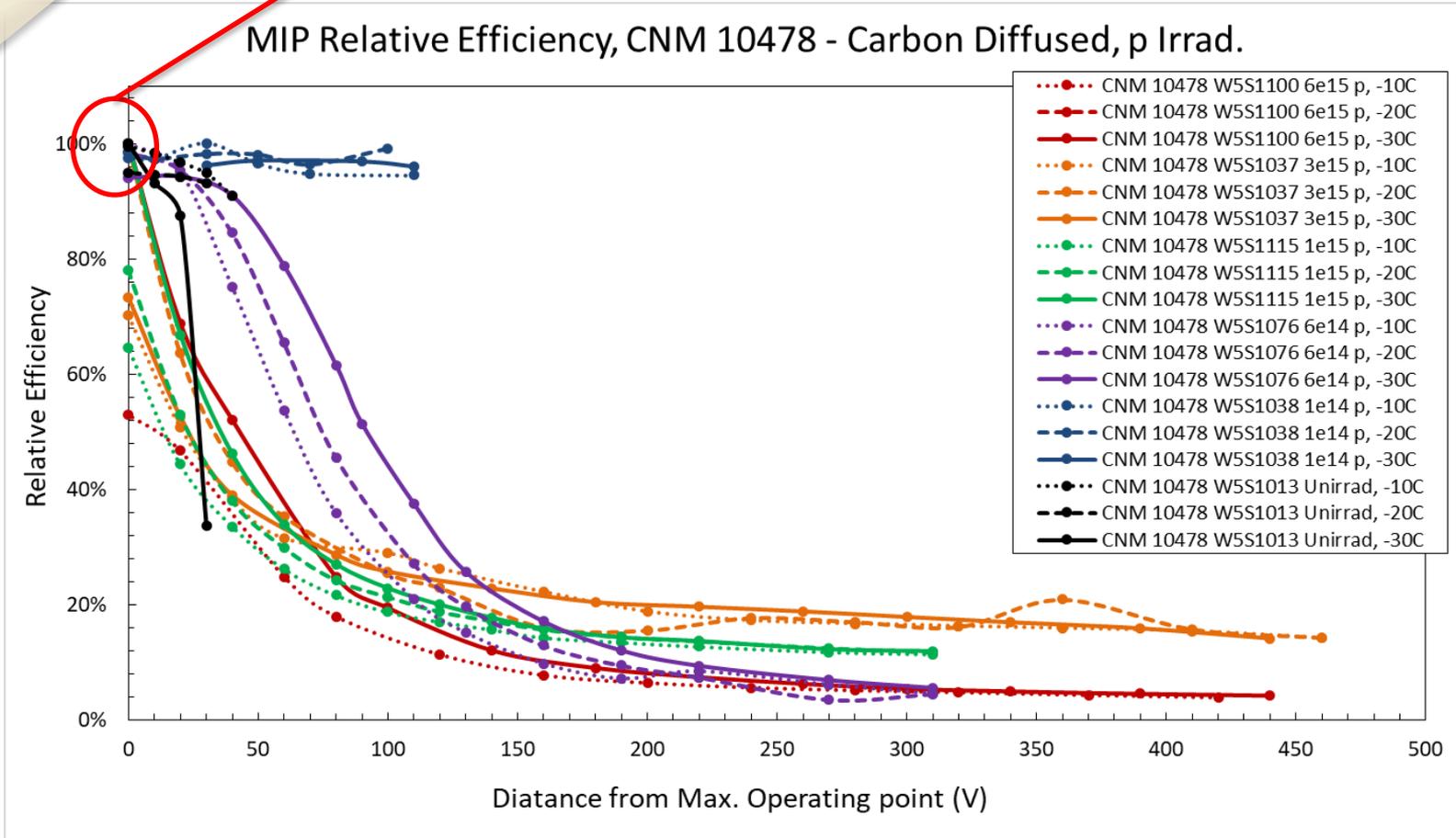


• Inter-pad distance studies

CNM 10478, Wafer 5, Carbon Implanted

⁹⁰Sr source data

auto triggering (artificially increase efficiency)



• Damaged sensor list

2018 - 19 CNM Unrecoverable sensors



Run	Wafer	Structure	Rad. Fluence	Species	GR Grounded	Discharge marks	Annealing	Conditions	
10478	W4	S1017	3e15	n	no	Pad	0 min	Pion beam	} <i>April Test Beam</i>
10478	W4	S1025	3e15	p	no	Pad	0 min	IVs on probe	
10478	W4	S1058	1e15	p	no	Pad	0 min	Pion beam	
10478	W4	S1102	6e15	n	no	Pad	0 min	Pion beam	
10478	W5	S1036	6e14	p	yes	GR	0 min	Pion beam	} <i>June Test Beam</i>
10478	W5	S1075	3e35	p	yes	GR	0 min	Pion beam	
10478	W5	S1117P	6e14	p	yes	GR	0 min	Pion beam	
10478	W4	LG08	3e15	n	yes	Pad	0 min	IVs on card	} <i>Lab Measurement</i>
10924	W6	S1028	1e14	p	yes	none	0 min	Pion beam	} <i>September Test Beam</i>
10924	W6	S1026	1e15	p	yes	GR	0 min	Pion beam	
10924	W6	S1025	3e15	p	yes	GR	0 min	Pion beam	
10924	W4	S1020	6e15	n	yes	Pad - GR	0 min	IVs on probe	} <i>Lab Measurement</i>
10478	W5	S1100	6e15	p	yes	?/?	0 min	β measurement	

Dead sensors sent back to manufactures for investigation

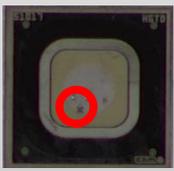
• Damaged sensor list

Visual inspection

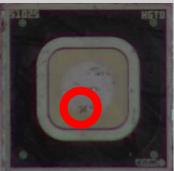
Normal

Carbon

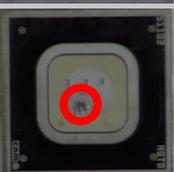
Gallium

W4S1017 

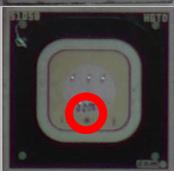
April 2018, 120GeV pion beam
Rate issues @ 620V, -30°C, N₂
(neutrons 3e15 n_{eq}/cm²)

W4S1025 

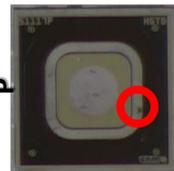
April 2018, died during IVs
Dielectric discharge @ 720V
-30°C, N₂
(protons 3e15 n_{eq}/cm²)

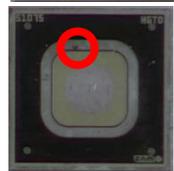
W4S1102 

April 2018, 120GeV pion beam, Rate issues @ 620V
-30°C, N₂
(neutrons 6e15 n_{eq}/cm²)

W4S1058 

April 2018, 120GeV pion beam, Rate issues @ 580V
-20°C, N₂ / **-30°C completed**
(protons 1e15 n_{eq}/cm²)

W5S1117 

W5S1075 

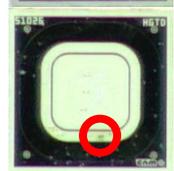
W5S1036 

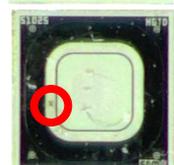
June 2018, 120GeV pion beam, Rate issues @ 620V, -30°C, N₂
(protons 6e14 n_{eq}/cm²)

June 2018, 120GeV pion beam,
Rate issues @ 600V, -30°C, N₂
(protons 3e15 n_{eq}/cm²)

June 2018, 120GeV pion beam
Died during alignment
Rate issues @ 600V, -30°C, N₂
(protons 6e14 n_{eq}/cm²)

W6S1028 

W6S1026 

W6S1025 

September 2018, data taking
Rate issues @ 220V
-20°C, N₂ / **-30°C completed**
(protons 1e14 n_{eq}/cm²)

September 2018, data taking
Rate issues @ 590V
-20°C, N₂ / **-30°C completed**
(protons 1e15 n_{eq}/cm²)

September 2018, data taking
Rate issues @ 590V -30°C, N₂
(protons 3e15 n_{eq}/cm²)

GR grounded – GR Discharge

GR not grounded – Pad Discharge

• Damaged sensor list

Visual inspection

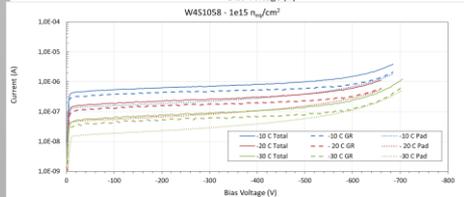
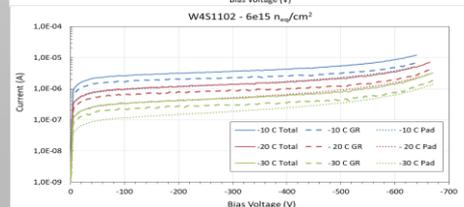
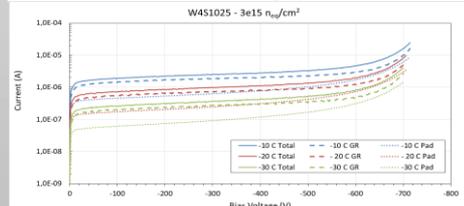
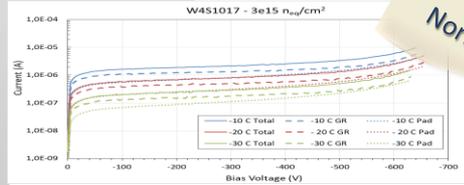
Where they really bad sensors?? – not according to their IVs

W4S101
7

W4S1025

W4S1102

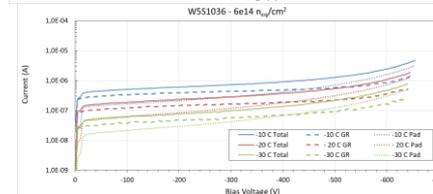
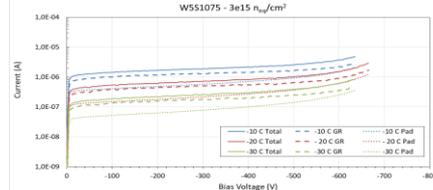
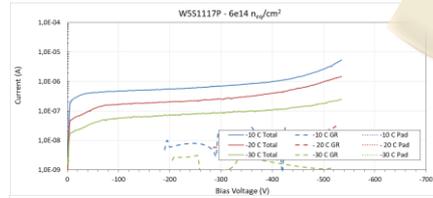
W4S1058



W5S1117
P

W5S1075

W5S1036

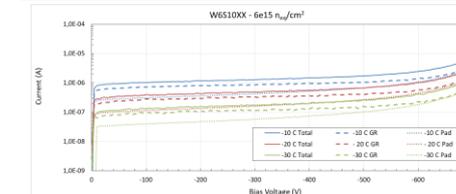
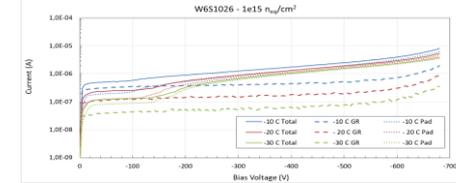
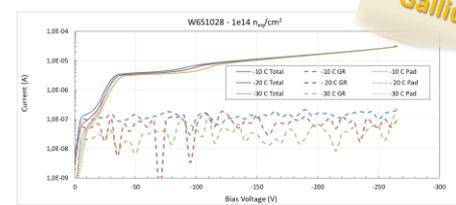


Carbon

W6S1028

W6S1026

W6S1025



Gallium

•Conclusions

Head room and efficiency

- We can achieve $\sim 100\%$ efficiency for Carbon+Boron and Boron only for up to $1e15$ at neutron irradiation
- For proton irradiation we achieve 100% efficiency at $1e15$ only for boron only sensors
- It seems that boron only at $3e15$ neutron is close to a 100% , more study is needed
- Boron only sensors provide larger headroom at 100% efficiency than boron + carbon combination
- Proton irradiation is more damaging than neutrons if correct scaling factors are applied, reality is somewhere in the middle
- In best case scenario (boron at $3e15$ neutrons) no safety factor is present